MR-1	Sak	Si-Di	Rr, Uni, 400V, 1,2A, Uf<0,91V(1,5A)	31a	SOD-18	BYD 33 M	31a	BY 226…227, BY 252…255, 1N5395…99, ++
MR-1 C		Si-Di	=MR-1: 1000V	31a	SOD-18	BYD 33 M	31a	BY 227, BY 255, GP 15M, 1N5399, ++
MR-1 Z		Si-Di	=MR-1: 200V	31a	SOD-18	BYD 33 M	31a	BY 226…227, BY 251…255, 1N5393…99,++
MR 1-1000	Mot	Si-Di	Rr, 1000V, 1A, Uf<1,3V(3,14A), <25µs	31a	DO-41	BYD 33 M	31a	BY 228, BYD 33M, EM 513, GP 10Q…Y, ++
MR 1-1200		Si-Di	=MR 1-1000: 1200V	31a	DO-41	BY 228	31a	BY 228, BY 448, EM 513, GP 10Q…Y, ++
MR 1-1400		Si-Di	=MR 1-1000: 1400V	31a	DO-41	BY 228	31a	BY 228, BY 448, EM 516, GP 10V…Y, ++
MR 1-1600		Si-Di	=MR 1-1000: 1600V	31a	DO-41	BY 228	31a	BY 228, BY 448, EM 516, DM 513, GP 10Y
MR 05	Ssc	Si-Di	Rr, S, 50V, 0,1/0,6A, Uf<1V(0,1A), <1µs	31a	DO-7	BA 159	31a	BA 157…159, BAY 18…21, BY 204/4, ++
MR 11	Ssc	Si-Di	=MR 05: 100V	31a	DO-7	BA 159	31a	BA 157…159, BAY 19…21, BY 204/4, ++
MR 21	Ssc	Si-Di	=MR 05: 250V	31a	DO-7	BA 159	31a	BA 157…159, BAY 21, BAY 46, BY 204/4,++
MR 31	Ssc	Si-Di	=MR 05: 350V	31a	DO-7	BA 159	31a	BA 157…159, BAY 89, BY 204/4, ++
MR 41	Ssc	Si-Di	=MR 05: 450V	31a	DO-7	BA 159	31a	BA 158…159, BAY 89, BY 204/8, ++
MR 52 Z	Ssc	Si-Di	FRr, contr.av., 500V, 0,2A, Uf<1V(0,2A), <200ns	31a	DO-7			BYX 57/500
MR 62 Z	Ssc	Si-Di	=MR 52Z: 600V	31a	DO-7			BYX 57/600
MR 250-1	Mot	Si-Di	kV-Rr, 1kV, 0,25A, Uf<3,5V(0,25A)	31a	SOD-22			GP 02-20, 1N1732A
MR 250-2		Si-Di	=MR 250-1: 2kV	31a	SOD-22			GP 02-20, 1N1732A
MR 250-3		Si-Di	=MR 250-1: 3kV	31a	SOD-22			GP 02-30, 1N1733A
MR 250-4		Si-Di	=MR 250-1: 4kV	31a	SOD-22			GP 02-40, 1N1734A
MR 250-5		Si-Di	=MR 250-1: 5kV	31a	SOD-22			1N1734A
MR 251		Si-Di	=BY 251	31a		BY 255	31a	›BY 251
MR 500	Mot	Si-Di	Rr, 50V, 3A, Uf<1,1V(9,4A)	31a	DO-27	BY 255	31a	BY 251…255, GP 30A…M, 1N5400…08, ++
MR 501	Mot	Si-Di	=MR 500: 100V	31a	DO-27	BY 255	31a	BY 251…255, GP 30B…M, 1N5401…08, ++
MR 502	Mot	Si-Di	=MR 500: 200V	31a	DO-27	BY 255	31a	BY 251…255, GP 30D…M, 1N5402…08, ++
MR 504	Mot	Si-Di	=MR 500: 400V	31a	DO-27	BY 255	31a	BY 252…255, GP 30G…M, 1N5404…08, ++
MR 506	Mot	Si-Di	=MR 500: 600V	31a	DO-27	BY 255	31a	BY 253…255, GP 30J…M, 1N5406…08, ++
MR 508	Mot	Si-Di	=MR 500: 800V	31a	DO-27	BY 255	31a	BY 254…255, GP 30K…M, 1N5407…08, ++
MR 510	Mot	Si-Di	=MR 500: 1000V	31a	DO-27	BY 255	31a	BY 228, BY 255, GP 30M, 1N5408, ++
MR 750	Mot	Si-Di	Rr, 50V, 6A, Uf<0,9V(6A)	31a	(6x9mmØ)	BY 500/800[7]	31a	BY 214/50…/1000
MR 751	Mot	Si-Di	=MR 750: 100V	31a	(6x9mmØ)	BY 500/800[7]	31a	BY 214/100…/1000
MR 752	Mot	Si-Di	=MR 750: 200V	31a	(6x9mmØ)	BY 500/800[7]	31a	BY 214/200…/1000
MR 754	Mot	Si-Di	=MR 750: 400V	31a	(6x9mmØ)	BY 500/800[7]	31a	BY 214/400…/1000
MR 756	Mot	Si-Di	=MR 750: 600V	31a	(6x9mmØ)	BY 500/800[7]	31a	BY 214/600…/1000
MR 758	Mot	Si-Di	=MR 750: 800V	31a	(6x9mmØ)	BY 500/800[7]	31a	BY 214/800…/1000
MR 760	Mot	Si-Di	=MR 750: 1000V	31a	(6x9mmØ)	BY 329/1200[6]	17k	BY 214/1000
MR 810	Mot	Si-Di	FRr, 50V, 1A, Uf<1,2V(1A), <750ns	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10A…M, ++
MR 811	Mot	Si-Di	=MR 810: 100V	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10B…M, ++
MR 812	Mot	Si-Di	=MR 810: 200V	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10D…M, ++
MR 813	Mot	Si-Di	=MR 810: 300V	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10G…M, ++
MR 814	Mot	Si-Di	=MR 810: 400V	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10G…M, ++
MR 816	Mot	Si-Di	=MR 810: 600V	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10J…M, ++
MR 817	Mot	Si-Di	=MR 810: 800V	31a	DO-41	BYD 33 M	31a	BY 231/800, BY 245/800, RGP 10K…M, ++
MR 818	Mot	Si-Di	=MR 810: 1000V	31a	DO-41	BYD 33 M	31a	BY 231/1000, BY 245/1200, RGP 10M, ++
MR 820	Mot, Die	Si-Di	FRr, 50V, 5A, Uf<1,1V(5A), <200ns	31a	(5x9mmØ)	BY 500/800	31a	FE 5A, EGP 50A, BY 500/100, (RGP 80A,++)[6]
MR 821	Mot, Die	Si-Di	=MR 820: 100V	31a	(5x9mmØ)	BY 500/800	31a	FE 5B, EGP 50B, BY 500/100, (RGP 80B,++)[6]
MR 822	Mot, Die	Si-Di	=MR 820: 200V	31a	(5x9mmØ)	BY 500/800	31a	FE 5D, EGP 50D, BY 500/200, (RGP 80D.++)[6]
MR 824	Mot, Die	Si-Di	=MR 820: 400V	31a	(5x9mmØ)	BY 500/800	31a	EGP 50G, BY 500/400, (RGP 80G,++)[6]
MR 826	Mot, Die	Si-Di	=MR 820: 600V	31a	(5x9mmØ)	BY 500/800	31a	BY 500/600, (BY 359/1000, RGP 80J,++)[6]
MR 828	Mot, Die	Si-Di	=MR 820: 800V	31a	(5x9mmØ)	BY 500/800	31a	BY 500/800, (BY 359/1000, RGP 80K,++)[6]
MR 830	Mot	Si-Di	FRr, 50V, 3A, Uf<1,1V(3A), <200ns	34b	DO-1	BYW 95 C	31a	BY 318/100, BY 396, BYW 72, BYW 95A, ++
MR 831	Mot	Si-Di	=MR 830: 100V	34b	DO-1	BYW 95 C	31a	BY 318/100, BY 396, BYW 72, BYW 95A, ++
MR 832	Mot	Si-Di	=MR 830: 200V	34b	DO-1	BYW 95 C	31a	BY 318/200, BY 397, BYW 72, BYW 95A, ++
MR 834	Mot	Si-Di	=MR 830: 400V	34b	DO-1	BYW 95 C	31a	BY 318/400, BY 398, BYW 74, BYW 95B, ++
MR 836	Mot	Si-Di	=MR 830: 600V	34b	DO-1	BYW 95 C	31a	BY 318/600, BY 399, BYW 76, BYW 95C, ++
MR 840….846	Mot	Si-Di	=MR 830…836: Uf<1,2V(3A), <1µs	31a	DO-1	RGP 30 M	31a	›MR 830…836
MR 850	Mot	Si-Di	FRr, 50V, 3A, Uf<1,25V(3A), <200ns	31a	DO-27	BYW 95 C	31a	BY 318/100, BY 396, BYW 72, BYW 95A, ++
MR 851	Mot	Si-Di	=MR 850: 100V	31a	DO-27	BYW 95 C	31a	BY 318/100, BY 396, BYW 72, BYW 95A, ++
MR 852	Mot	Si-Di	=MR 850: 200V	31a	DO-27	BYW 95 C	31a	BY 318/200, BY 397, BYW 72, BYW 95A, ++
MR 854	Mot	Si-Di	=MR 850: 400V	31a	DO-27	BYW 95 C	31a	BY 318/400, BY 398, BYW 74, BYW 95B, ++
MR 856	Mot	Si-Di	=MR 850: 600V	31a	DO-27	BYW 95 C	31a	BY 318/600, BY 399, BYW 76, BYW 95C, ++
MR 860	Mot	Si-Di	P FRr, 50V, 40A(Tc=100°), Uf<1,4V(40A), <200ns	32a	DO-5			BYW 25/800, BYW 78/50, BYW 93/50, MR 870
MR 860 R		Si-Di	=MR 860:	32b	DO-5			BYW 25/800R, BYW 78/50R, MR 870R
MR 861	Mot	Si-Di	=MR 860: 100V	32a	DO-5			BYW25/800, BYW78/100, BYW93/100, MR871
MR 861 R		Si-Di	=MR 861:	32b	DO-5			BYW 25/800R, BYW 78/100R, MR 871R
MR 862	Mot	Si-Di	=MR 860: 200V	32a	DO-5			BYW25/800, BYW78/200, BYW93/200, MR872
MR 862 R		Si-Di	=MR 862:	32b	DO-5			BYW 25/800R, BYW 78/200R, MR 872R
MR 864	Mot	Si-Di	=MR 860: 400V	32a	DO-5			BYW 25/800, MR 874
MR 864 R		Si-Di	=MR 864:	32b	DO-5			BYW 25/800R, MR 874R
MR 866	Mot	Si-Di	=MR 860: 600V	32a	DO-5			BYW 25/800, MR 876
MR 866 R		Si-Di	=MR 866:	32b	DO-5			BYW 25/800R, MR 876R
MR 870	Mot	Si-Di	P FRr, 50V, 50A(Tc=100°), Uf<1,4V(50A), <200ns	32a	DO-5			BYT 60/200, BYW 78/50, BYW 93/50
MR 870 R		Si-Di	=MR 870:	32b	DO-5			BYT 60/200R, BYW 78/50R
MR 871	Mot	Si-Di	=MR 870: 100V	32a	DO-5			BYT 60/200, BYW 78/100, BYW 93/100
MR 871 R		Si-Di	=MR 871:	32b	DO-5			BYT 60/200R, BYW 78/100R
MR 872	Mot	Si-Di	=MR 870: 200V	32a	DO-5			BYT 60/200, BYW 78/200, BYW 93/200
MR 872 R		Si-Di	=MR 872:	32b	DO-5			BYT 60/200R, BYW 78/200R
MR 874	Mot	Si-Di	=MR 870: 400V	32a	DO-5			BYT 60/400
MR 874 R		Si-Di	=MR 874:	32b	DO-5			BYT 60/400R
MR 876	Mot	Si-Di	=MR 870: 600V	32a	DO-5			-
MR 876 R		Si-Di	=MR 876:	32b	DO-5			-
MR 880	Mot	Si-Di	P FRr, 50V, 12A(Tc=100°), Uf<1,4V(12A), <1µs	32a	DO-4			BYT 61/600, BYX 30/200, BYX 61/50, ++
MR 881	Mot	Si-Di	=MR 880: 100V	32a	DO-4			BYT 61/600, BYX 30/200, BYX 61/100, ++
MR 882	Mot	Si-Di	=MR 880: 200V	32a	DO-4			BYT 61/600, BYX 30/200, BYX 61/200, ++
MR 884	Mot	Si-Di	=MR 880: 400V	32a	DO-4			BYT 61/600, BYX 30/400, BYX 61/400, ++
MR 886	Mot	Si-Di	=MR 880: 600V	32a	DO-4			BYT 61/600, BYX 30/600, BYX 61/600, ++
MR 890	Mot	Si-Di	P FRr, 50V, 30A(Tc=100°), Uf<1,4V(30A), <1µs	32a	DO-5			BYT 65/600, BYX 64/600, BYX 67/400, ++
MR 891	Mot	Si-Di	=MR 890: 100V	32a	DO-5			BYT 65/600, BYX 64/600, BYX 67/400, ++
MR 892	Mot	Si-Di	=MR 890: 200V	32a	DO-5			BYT 65/600, BYX 64/600, BYX 67/400, ++
MR 894	Mot	Si-Di	=MR 890: 400V	32a	DO-5			BYT 65/600, BYX 64/600, BYX 67/400, ++
MR 896	Mot	Si-Di	=MR 890: 600V	32a	DO-5			BYT 65/600, BYX 64/600, BYX 67/600, ++
MR 910	Mot	Si-Di	FRr, 50V, 3A, Uf<1,1V(9,4A), <750ns	31a	DO-27A	RGP 30 M	31a	BY 318/100, BY 396, BYW 72, RGP 30A, ++
MR 911	Mot	Si-Di	=MR 910: 100V	31a	DO-27A	RGP 30 M	31a	BY 318/100, BY 396, BYW 72, RGP 30B, ++
MR 912	Mot	Si-Di	=MR 910: 200V	31a	DO-27A	RGP 30 M	31a	BY 318/200, BY 397, BYW 72, RGP 30D, ++
MR 914	Mot	Si-Di	=MR 910: 400V	31a	DO-27A	RGP 30 M	31a	BY 318/400, BY 398, BYW 74, RGP 30G, ++

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